

**Amendments to the Abstract:**

**Please rewrite the Abstract as follows:**

Abstract of the Disclosure

~~The present invention provides a~~ A semiconductive glaze product is provided,  
which exhibits low thermal expansion coefficient without adversely affecting other  
glaze characteristics, and which, when applied to an insulator, attains enhanced  
mechanical strength of the insulator; ~~a method for producing the semiconductive glaze  
product; and an insulator coated with the semiconductive glaze product.~~ The  
semiconductive glaze product contains a glaze composition and a flux. ~~the.~~ The glaze  
~~composition containing~~ contains a KNaO-MgO-CaO-Al<sub>2</sub>O<sub>3</sub>-SiO<sub>2</sub>-based base glaze, in  
which the compositional proportions of ~~basic components; i.e.,~~ KNaO, MgO, and  
CaO, as represented by the Seger formula, are 0.1 to 0.4, 0.2 to 0.6, and balance,  
respectively; ~~and containing.~~ The glaze composition contains a metal oxide  
composition including tin oxide and antimony oxide, wherein the amount of ~~the flux is~~  
10 parts by weight or less on the basis of 100 parts by weight of the glaze composition.